### UF28150J



### **RF Power MOSFET Transistor** 150W, 100MHz-500MHz, 28V

M/A-COM Products Released; RoHS Compliant

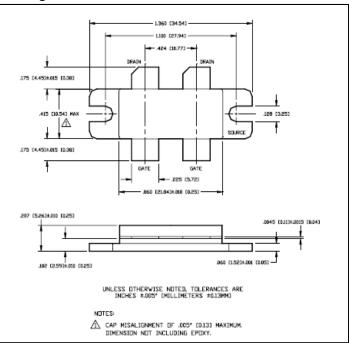
#### **Features**

- DMOS structure
- Lower capacitance for broadband operation
- Common source configuration

### **ABSOLUTE MAXIMUM RATINGS**<sup>1, 2, 3</sup>

Parameter	Symbol	Rating	Units
Drain-Source Voltage	$V_{DS}$	65	V
Gate-Source Voltage	$V_{GS}$	20	V
Drain-Source Current	I <sub>DS</sub>	16*	Α
Power Dissipation	$P_D$	389	W
Junction Temperature	TJ	200	°C
Storage Temperature	T <sub>STG</sub>	-65 to +150	°C
Thermal Resistance	Θ <sub>JC</sub>	0.45	°C/W

### **Package Outline**



- 1. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 2. M/A-COM does not recommend sustained operation near these maximum limits.
- 3. At 25°C Tcase, unless noted.

#### **ELECTRICAL SPECIFICATIONS: 25°C**

Parameter	Test Conditions	Units	Min.	Max.
Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0.0 V, I <sub>DS</sub> = 20.0 mA*	BV <sub>DSS</sub>	65	_
Drain-Source Leakage Current	V <sub>DS</sub> = 28.0 V, V <sub>GS</sub> = 0.0V*	I <sub>DSS</sub>	_	4.0
Gate-Source Leakage Current	V <sub>GS</sub> = 20 V, V <sub>DS</sub> = 0.0 V*	I <sub>GSS</sub>	_	4.0
Gate Threshold Voltage	V <sub>DS</sub> = 10.0 V, I <sub>DS</sub> = 400.0 mA*	$V_{\text{GS(TH)}}$	2.0	6.0
Forward Transconductance	$V_{DS}$ = 10.0 V, $I_{DS}$ = 4000.0 mA, $\Delta V_{GS}$ = 1.0 V, 80µs pulse*	G <sub>M</sub>	2.0	_
Input Capacitance	V <sub>DS</sub> = 28.0V, F = 1.0 MHz*	C <sub>ISS</sub>	_	180
Output Capacitance	V <sub>DS</sub> = 28.0V, F = 1.0 MHz*	Coss	_	120
Reverse Capacitance	V <sub>DS</sub> = 28.0V, F = 1.0 MHz*	C <sub>RSS</sub>	_	32
Power Gain	V <sub>DD</sub> = 28.0 V, I <sub>DQ</sub> = 400.0 mA, P <sub>OUT</sub> = 150.0 W, F = 500 MHz	G <sub>P</sub>	8	_
Drain Efficiency	V <sub>DD</sub> = 28.0 V, I <sub>DQ</sub> = 400.0 mA, P <sub>OUT</sub> = 150.0 W, F = 500 MHz	$\eta_{D}$	55	_
Load Mismatch Tolerance	$V_{DD}$ = 28.0 V, $I_{DQ}$ = 400.0 mA, $P_{OUT}$ = 150.0 W, F = 500 MHz	VSWR-T	_	10:1**

#### Notes:

- \* Per side
- \*\* At all phase angles

Commitment to produce in volume is not guaranteed.

• North America Tel: 800.366.2266 / Fax: 978.366.2266

• Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

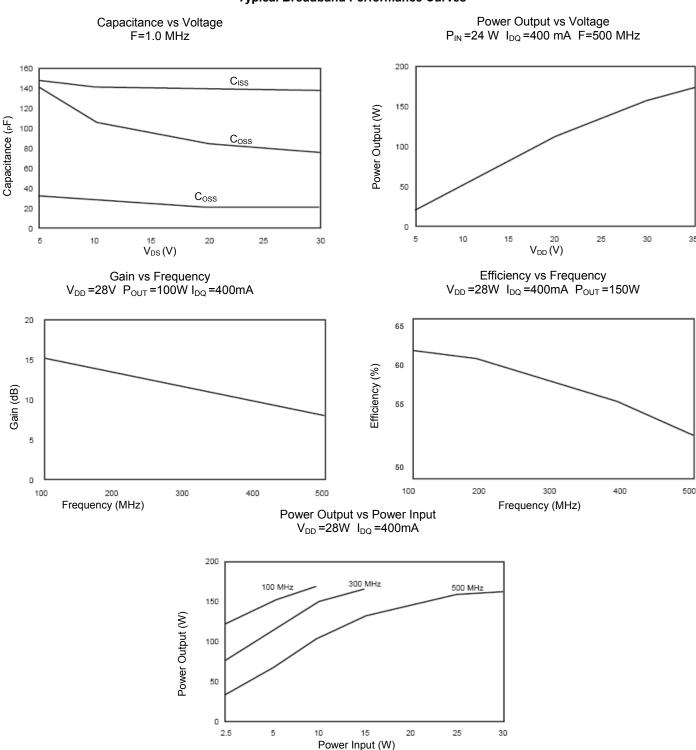
Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298



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### **Typical Broadband Performance Curves**



and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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  Visit www.macomtech.com for additional data sheets and product information.

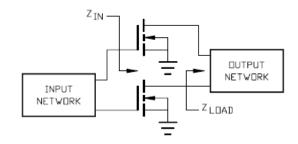


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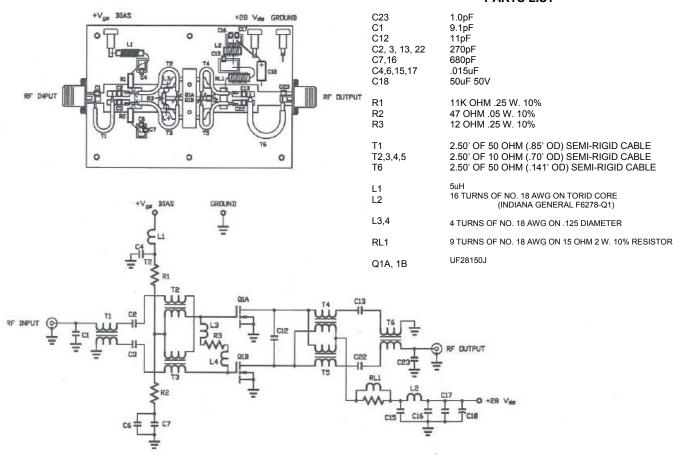
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### TYPICAL OPTIMUM DEVICE IMPEDANCES

F (MHz)	Z <sub>IN</sub> (Ω)	Z <sub>LOAD</sub> (Ω)		
100	3.7 - j5.9	3.0 - j0.7		
300	2.7 - j5.9	2.6 - j0.55		
500	2.5 - j2.9	2.5 - j0.5		
$V_{DD}$ = 28V, $I_{DQ}$ = 400mA, $P_{OUT}$ = 150W				



### **PARTS LIST**



### HANDLING PROCEDURES: STATIC SENSITIVITY

Commitment to produce in volume is not guaranteed.

Please observe the following precautions to avoid damage:

DMOS devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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